

DATASHEET

Opto Interrupter ITR9608-F

Features

- Fast response time
- High analytic
- Cut-off visible wavelength λp=940nm
- · High sensitivity
- Pb free
- This product itself will remain within RoHS compliant version

Description

- The ITR9608-F consist of an infrared emitting diode and an NPN silicon phototransistor, encased side-by-side on converging optical axis in a black thermoplastic housing,
- The phototransistor receives radiation from the IRED only .This is the normal situation.
- But when an object is in between , phototransistor could not receives the radiation.
- For additional component information, please refer to IR928-6C and PT928-6C

Applications

- Mouse Copier
- Switch Scanner
- Floppy disk driver
- Non-contact Switching
- For Direct Board

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Device Selection Guide

Device No.	Chip Materials	Lens Color		
IR	GaAlAs	Water clear		
PT	Silicon	Water clear		

Absolute Maximum Ratings (Ta=25)

Parameter		Symbol	Ratings	Unit
Input	Power Dissipation at(or below) 25 Free Air Temperature	Pd	75	mW
	Reverse Voltage	V_R	5	V
	Forward Current	l _F	50	mA
	Peak Forward Current (*1) Pulse width 100µs, Duty cycle=1%	I _{FP}	1	А
Output	Collector Power Dissipation	Pd	75	mW
	Collector Current	Ic	20	mA
	Collector-Emitter Voltage	B V _{CEO}	30	V
	Emitter-Collector Voltage	B V _{ECO}	5	V
Operating Temperature		Topr	-25~+85	
Storage Temperature		Tstg	-40~+85	
Lead Soldering Temperature (*2) (1/16 inch form body for 5 seconds)		Tsol	260	

(*1) tw=100 μsec. , T=10 msec. (*2) t=5 Sec

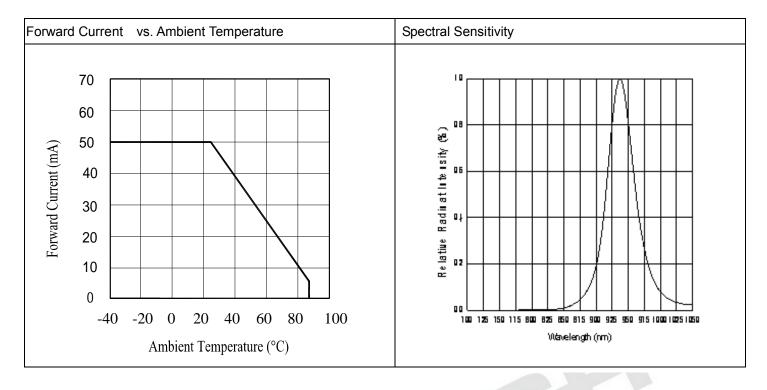


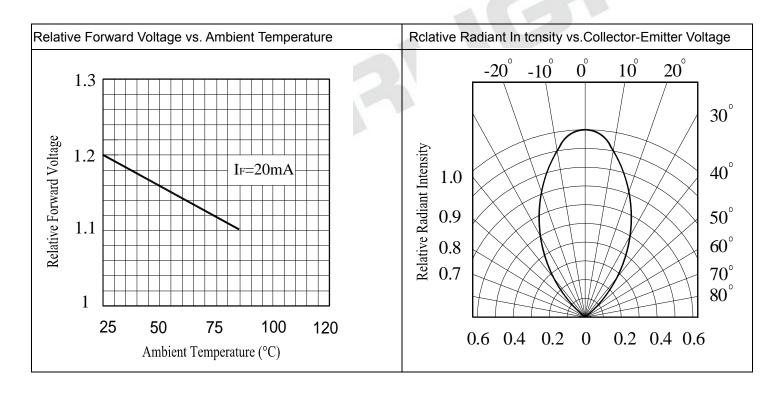
Electro-Optical Characteristics (Ta=25)

Parameter		Symbol	Min.	Тур.	Max.	Unit	Conditions			
	Forward Voltage	V_{F}		1.2	1.5	V	I _F =20mA			
Input	Reverse Current	I _R			10	μA	V _R =5V			
	Peak Wavelength	λ_{P}		940		nm	I _F =20mA			
Output	Dark C urrent	I _{CEO}			100	nA	V _{CE} =20V,Ee=0mW/cm ²			
	C-E Saturation Voltage	V _{CE} (sat)			0.4	V	I _C =2mA ,Ee=1mW/cm ²			
Transfer	Collect Current	I _C (ON)	0.5			mA	V _{CE} =5V I _F =20mA			
Transfer Characteristics	Rise time	t _r		15		µsec	V _{CE} =5V I _C =1mA			
	Fall time	t _f		15		µsec	$R_L=1K\Omega$			



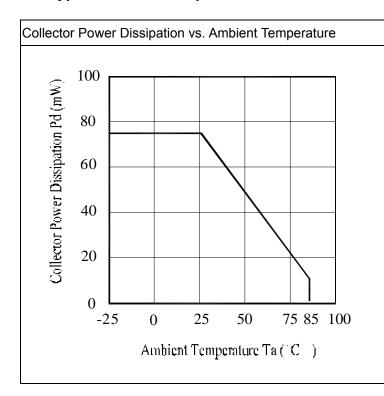
Typical Electrical/Optical/Characteristics Curves for IR

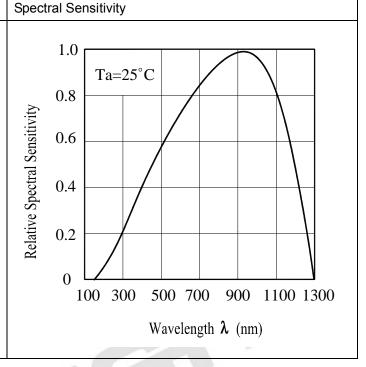


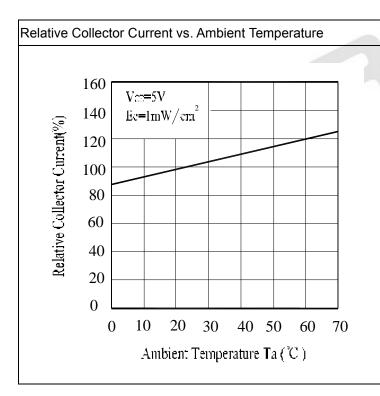


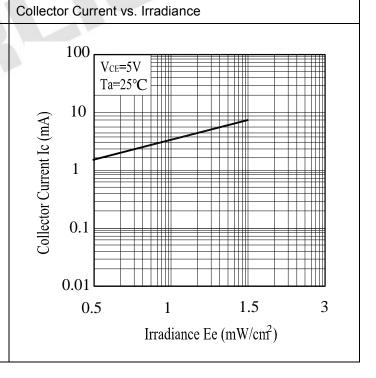


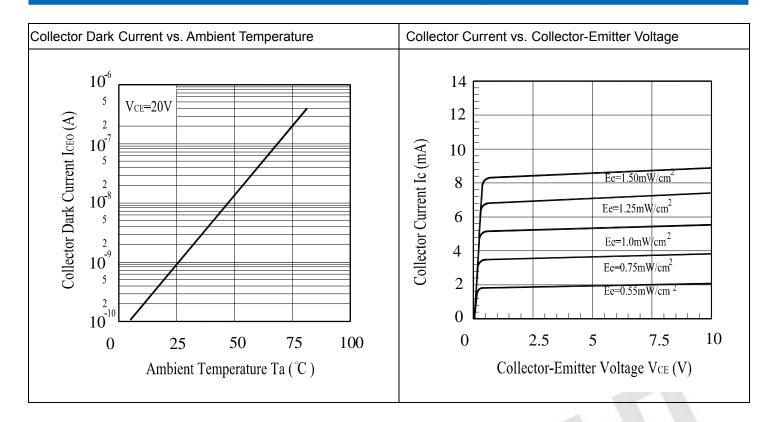
Typical Electrical/Optical/Characteristics Curves for PT





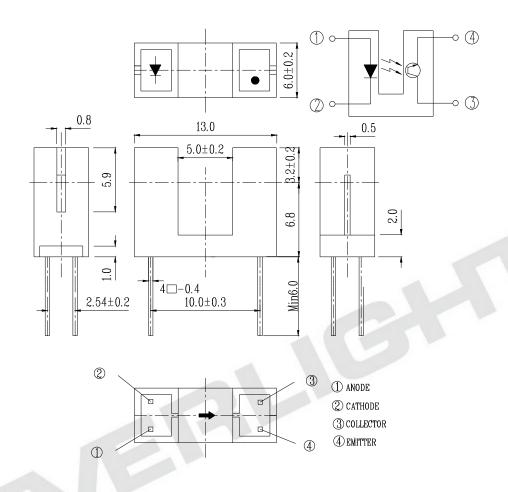








Package Dimension



Note: Tolerances unless dimensions ±0.25mm



Packing Quantity Specification

- 1. 150PCS/1Bag, 4Bags/1Box
- 2. 10Boxes/1Carton

Label Form Specification



- CPN: Customer's Product Number
- P/N: Product Number
- · QTY: Packing Quantity
- · CAT: Luminous Intensity Rank
- · HUE: Dom. Wavelength Rank
- REF: Forward Voltage Rank
- · LOT No: Lot Number
- X: Month
- · Reference: Identify Label Number

Notes

- 1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 2. When using this product, please observe the absolute maximum ratings and the instruction for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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